WEST Search History

DATE: Friday, May 23, 2003

Set Name side by side	Query	Hit Count	Set Name result set
DB=US	PT,PGPB,JPAB,EPAB,DWPI,TDBD; PLUR=YES; OP=OR		
L8	L7 and (display or LCD)	391	L8
L7	L6 and silicon and TEOS	803	L7
L6	(voltage with (rais\$4 or higher or greater or larger or bigger or ramp\$3 or shift\$4 or mov\$3 or toggl\$3 or oscillat\$4)) and (PECVD or (plasma near3 CVD))	4023	L6
L5	L4 and (voltage with (rais\$4 or higher or greater or larger or bigger or ramp\$3 or shift\$4 or mov\$3 or toggl\$3 or oscillat\$4))	54	L5
L4	(voltage with between with electrode\$1) same (PECVD or (plasma near3 CVD))	218	L4
DB=US	PT; PLUR=YES; OP=OR		
L3	L2 and voltage	1	L3
L2	5585149.pn.	1	L2
L1	(PECVD or (plasma with CVD)) and (introduc\$3 with after with voltage) and (electrode\$1 with voltage\$1)	61	L1

END OF SEARCH HISTORY



DATE: Friday, May 23, 2003

Set Name side by side	Query	Hit Count	Set Name result set
•	PT,PGPB,JPAB,EPAB,DWPI,TDBD; PLUR=YES; OP=OR		
L11	L10 and (increas\$3 with voltage with between with electrode\$1)	332	L11
L10	(PECVD or (plasma near3 CVD))	34512	L10
L9	L8 not (semiconductor and energy and laboratory).as.	230	L9
L8	L7 and (display or LCD)	391	L8
L7	L6 and silicon and TEOS	803	L7
L6	(voltage with (rais\$4 or higher or greater or larger or bigger or ramp\$3 or shift\$4 or mov\$3 or toggl\$3 or oscillat\$4)) and (PECVD or (plasma near3 CVD))	4023	L6
L5	L4 and (voltage with (rais\$4 or higher or greater or larger or bigger or ramp\$3 or shift\$4 or mov\$3 or toggl\$3 or oscillat\$4))	54	L5
L4	(voltage with between with electrode\$1) same (PECVD or (plasma near3 CVD))	218	L4
DB = US	SPT; PLUR = YES; OP = OR		
L3	L2 and voltage	1	L3
L2	5585149.pn.	1	L2
L1	(PECVD or (plasma with CVD)) and (introduc\$3 with after with voltage) and (electrode\$1 with voltage\$1)	61	L1

END OF SEARCH HISTORY